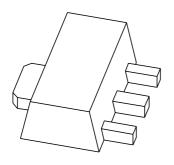
### DISCRETE SEMICONDUCTORS

# DATA SHEET



## BCX54; BCX55; BCX56 NPN medium power transistors

Product specification Supersedes data of 1999 Apr 19 2001 Oct 10





### NPN medium power transistors

### BCX54; BCX55; BCX56

#### **FEATURES**

- High current (max. 1 A)
- Low voltage (max. 80 V).

### **APPLICATIONS**

• Driver stages of audio and video amplifiers.

### **DESCRIPTION**

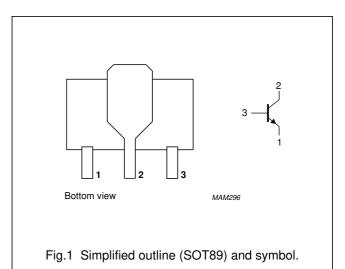
NPN medium power transistor in a SOT89 plastic package. PNP complements: BCX51, BCX52 and BCX53.

#### **MARKING**

TYPE NUMBER	MARKING CODE		
BCX54	BA	BCX55-16	ВМ
BCX54-10	BC	BCX56	BH
BCX54-16	BD	BCX56-10	BK
BCX55	BE	BCX56-16	BL
BCX55-10	BG		

### **PINNING**

PIN	DESCRIPTION
1	emitter
2	collector
3	base



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### NPN medium power transistors

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#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter			
	BCX54		_	45	V
	BCX55		_	60	V
	BCX56		_	100	V
V <sub>CEO</sub>	collector-emitter voltage	open base			
	BCX54		_	45	V
	BCX55		_	60	V
	BCX56		_	80	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	5	V
I <sub>C</sub>	collector current (DC)		_	1	Α
I <sub>CM</sub>	peak collector current		_	1.5	Α
I <sub>BM</sub>	peak base current		_	0.2	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	1.3	W
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

### Note

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	94	K/W
R <sub>th j-s</sub>	thermal resistance from junction to soldering point		14	K/W

#### Note

Device mounted on a printed-circuit board, single sided copper, tinplated, mounting pad for collector 6 cm<sup>2</sup>.
 For other mounting conditions, see "Thermal considerations for SOT89 in the General Part of associated Handbook".

<sup>1.</sup> Device mounted on a printed-circuit board, single sided copper, tinplated, mounting pad for collector 6 cm<sup>2</sup>. For other mounting conditions, see "Thermal considerations for SOT89 in the General Part of associated Handbook".

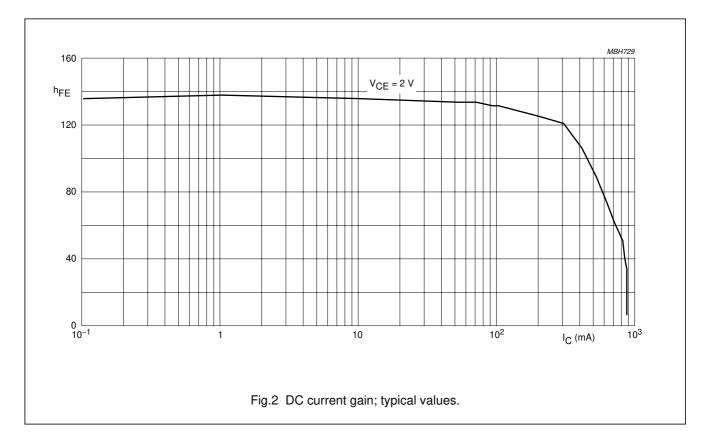
### NPN medium power transistors

BCX54; BCX55; BCX56

### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	I <sub>E</sub> = 0; V <sub>CB</sub> = 30 V	_	_	100	nA
		$I_E = 0$ ; $V_{CB} = 30 \text{ V}$ ; $T_j = 125  ^{\circ}\text{C}$	_	_	10	μΑ
I <sub>EBO</sub>	emitter cut-off current	I <sub>C</sub> = 0; V <sub>EB</sub> = 5 V	_	_	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 2 V; (see Fig.2)				
		$I_C = 5 \text{ mA}$	63	_	_	
		I <sub>C</sub> = 150 mA	63	_	250	
		I <sub>C</sub> = 500 mA	40	_	_	
	DC current gain	I <sub>C</sub> = 150 mA; V <sub>CE</sub> = 2 V; (see Fig.2)				
	BCX54-10; 55-10; 56-10		63	_	160	
	BCX54-16; 55-16; 56-16		100	_	250	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 500 mA; I <sub>B</sub> = 50 mA	_	_	0.5	V
V <sub>BE</sub>	base-emitter voltage	I <sub>C</sub> = 500 mA; V <sub>CE</sub> = 2 V	_	_	1	٧
f <sub>T</sub>	transition frequency	$I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}; f = 100 \text{ MHz}$	_	130	_	MHz
h <sub>FE1</sub> h <sub>FE2</sub>	DC current gain ratio of the complementary pairs	$ I_C  = 150 \text{ mA};  V_{CE}  = 2 \text{ V}$	_	1.3	1.6	



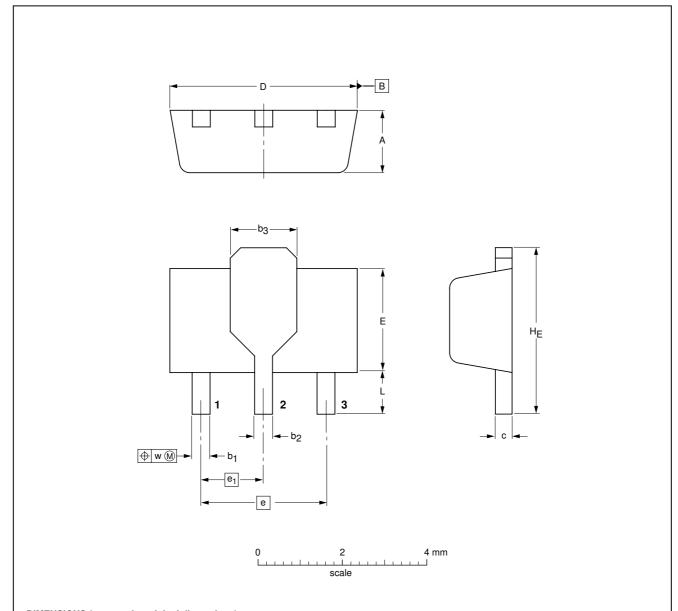
### NPN medium power transistors

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### **PACKAGE OUTLINE**

Plastic surface mounted package; collector pad for good heat transfer; 3 leads

**SOT89** 



### DIMENSIONS (mm are the original dimensions)

UNI	ГА	b <sub>1</sub>	b <sub>2</sub>	b <sub>3</sub>	С	D	E	е	e <sub>1</sub>	HE	L min.	w
mn	1.6 1.4	0.48 0.35	0.53 0.40	1.8 1.4	0.44 0.37	4.6 4.4	2.6 2.4	3.0	1.5	4.25 3.75	0.8	0.13

OUTLINE		REFER	ENCES	EUROPEAN ISSUE DAT		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT89		TO-243	SC-62		<del>97-02-28</del> 99-09-13	

### NPN medium power transistors

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DATA SHEET STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
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### NPN medium power transistors

BCX54; BCX55; BCX56

### **NOTES**

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#### **Contact information**

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